# 2SC1162

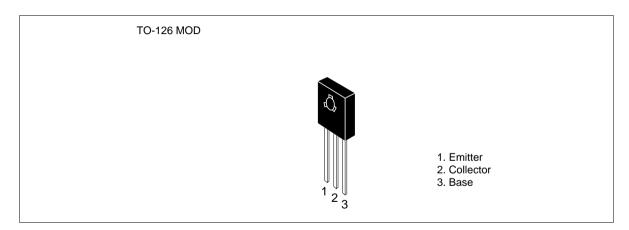
# Silicon NPN Epitaxial

# **HITACHI**

### **Application**

Low frequency power amplifier complementary pair with 2SA715

### Outline



## **Absolute Maximum Ratings** $(Ta = 25^{\circ}C)$

| Item                         | Symbol               | Ratings     | Unit |
|------------------------------|----------------------|-------------|------|
| Collector to base voltage    | $V_{\text{CBO}}$     | 35          | V    |
| Collector to emitter voltage | V <sub>CEO</sub>     | 35          | V    |
| Emitter to base voltage      | $V_{EBO}$            | 5           | V    |
| Collector current            | I <sub>c</sub>       | 2.5         | A    |
| Collector peak current       | I <sub>C(peak)</sub> | 3           | A    |
| Collector power dissipation  | P <sub>c</sub>       | 0.75        | W    |
|                              | P <sub>c</sub> *1    | 10          | W    |
| Junction temperature         | Tj                   | 150         | °C   |
| Storage temperature          | Tstg                 | -55 to +150 | °C   |

Note: 1. Value at  $T_c = 25^{\circ}C$ .



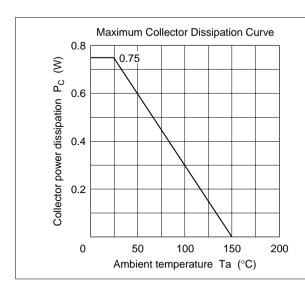
## 2SC1162

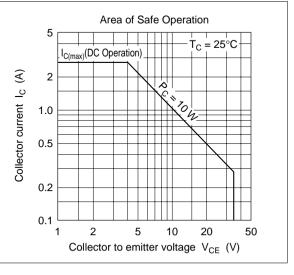
### **Electrical Characteristics** (Ta = 25°C)

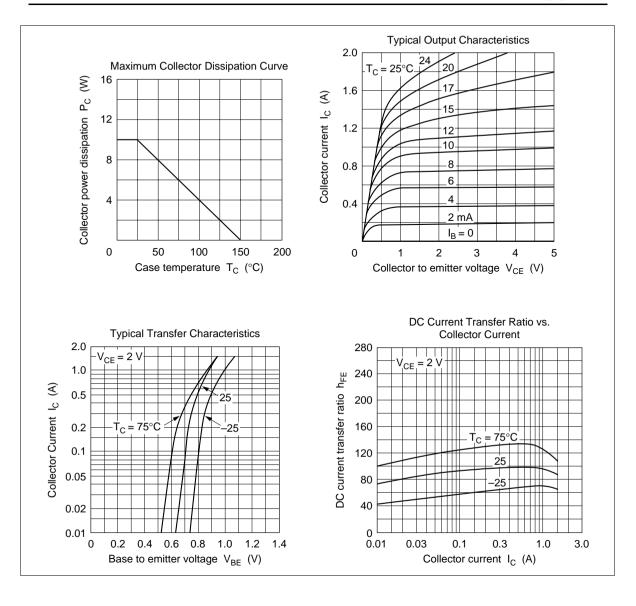
| Item                                    | Symbol               | Min | Тур  | Max | Unit | Test conditions  |
|---|----------------------|-----|------|-----|------|--|
| Collector to base breakdown voltage     | $V_{(BR)CBO}$        | 35  | _    | _   | V    | $I_{c} = 1 \text{ mA}, I_{E} = 0$                          |
| Collector to emitter breakdown voltage  | $V_{(BR)CEO}$        | 35  | _    | _   | V    | $I_{C}$ = 10 mA, $R_{BE}$ = $\infty$                       |
| Emitter to base breakdown voltage       | $V_{(BR)EBO}$        | 5   | _    | _   | V    | $I_{E} = 1 \text{ mA}, I_{C} = 0$                          |
| Collector cutoff current                | I <sub>CBO</sub>     | _   | _    | 20  | μΑ   | $V_{CB} = 35 \text{ V}, I_{E} = 0$                         |
| DC current transfer ratio               | h <sub>FE</sub> *1   | 60  | _    | 320 |      | $V_{CE} = 2 \text{ V}, I_{C} = 0.5 \text{ A}$              |
|   | h <sub>FE</sub>      | 20  | _    | _   |      | $V_{CE} = 2 \text{ V}, I_{C} = 1.5 \text{ A}$ (pulse test) |
| Base to emitter voltage                 | $V_{BE}$             | _   | 0.93 | 1.5 | V    | $V_{CE} = 2 \text{ V}, I_{C} = 1.5 \text{ A}$ (pulse test) |
| Collector to emitter saturation voltage | $V_{\text{CE(sat)}}$ | _   | 0.5  | 1.0 | V    | $I_C = 2 \text{ A}, I_B = 0.2 \text{ A (pulse test)}$      |
| Gain bandwidth product                  | f <sub>T</sub>       | _   | 180  | _   | MHz  | $V_{CE} = 2 \text{ V}, I_{C} = 0.2 \text{ A}$              |

Note: 1. The 2SC1162 is grouped by  $h_{FE}$  as follows.

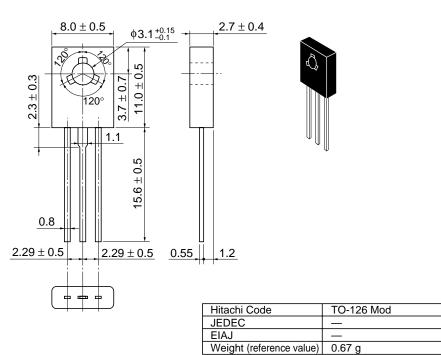
| В         | С          | D          |
|-----------|------------|------------|
| 60 to 120 | 100 to 200 | 160 to 320 |







Unit: mm



#### **Cautions**

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